



# ESDS302, ESDS304 Data-Line Surge and ESD Protection Devices for High Speed Interfaces

## 1 Features

- IEC 61000-4-2 Level 4 ESD Protection
  - $\pm 30$ -kV Contact Discharge
  - $\pm 30$ -kV Air Gap Discharge
- IEC 61000-4-4 EFT Protection
  - 80 A (5/50 ns)
- IEC 61000-4-5 Surge Protection
  - 12 A (8/20  $\mu$ s)
  - Low Surge Clamping Voltage 6 V at 12 A Ipp
- IO Capacitance:
  - 2.3 pF (Typical)
- DC Breakdown Voltage: 4.5 V (Minimum)
- Ultra Low Leakage Current: 3 nA (Typical)
- Supports High Speed Interfaces up to 1 Gbps
- Industrial Temperature Range:  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$
- Easy Flow-Through Routing Package (ESDS302)

## 2 Applications

- End Equipment
  - Ethernet Switches
  - Access Points
  - Gateways
  - Printers
  - DVR and NVR
- Interfaces
  - Ethernet 10/100/1000 Mbps
  - USB 2.0
  - GPIO

## 3 Description

The ESDS302, ESDS304 devices are bidirectional TVS ESD protection diode array in two and four channel configurations respectively, for Ethernet and USB surge protection up to 12 A (8/20  $\mu$ s). The ESDS302, ESDS304 devices are rated to dissipate ESD strikes up to 30 kV per the IEC 61000-4-2 international standard (> Level 4).

The devices features a 2.3-pF IO capacitance per channel making it ideal for protecting high-speed interfaces such as Ethernet 1G and USB 2.0. The low dynamic resistance and low clamping voltage ensure system level protection against transient events.

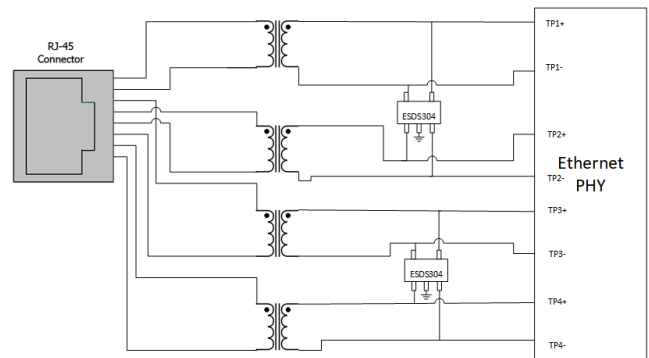
The ESDS302, ESDS304 devices are offered in the industry standard 5-Pin SOT23 packages.

### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
ESDS302	SOT23 (5); 2 NC pins	2.90 mm $\times$ 1.6 mm $\times$ 1.25 mm
ESDS304	SOT23 (5)	2.90 mm $\times$ 1.6 mm $\times$ 1.25 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

### Typical Application Schematic



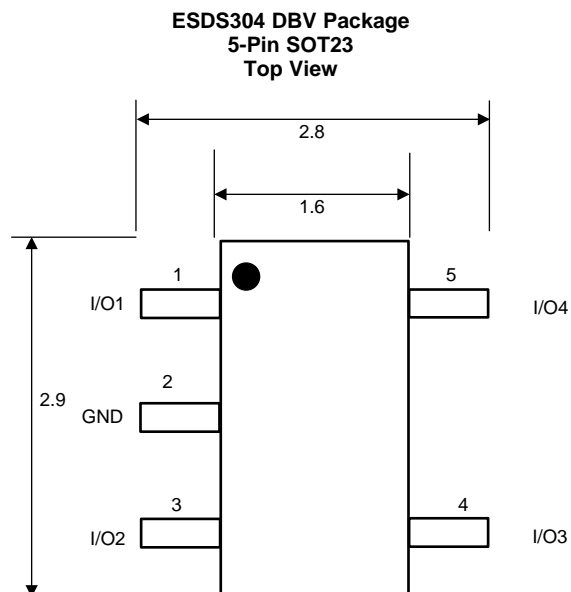
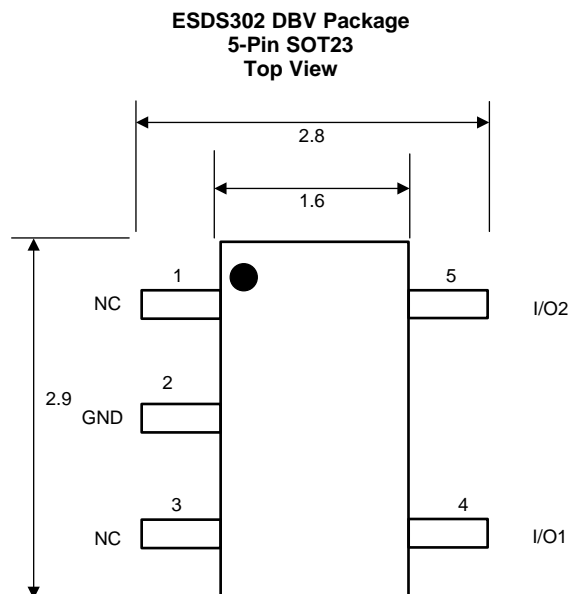
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## 4 Revision History

Changes from Original (May 2018) to Revision A	Page
• Changed data sheet status from Product Preview to Production Data .....	1
• Changed ESDS03802 and ESDS03804 part numbers to ESDS302 and ESDS304 .....	1

## 5 Pin Configuration and Functions



### Pin Functions for ESDS302

PIN		TYPE	DESCRIPTION
NAME	NO.		
I/O1	4	I/O	Surge/ESD protected channels. Connect to the lines being protected.
I/O2	5		
GND	2	GND	Ground. Connect to ground
NC	1	NC	Not connected; Used for optional straight-through routing. Can be left floating or grounded
NC	3		

### Pin Functions for ESDS304

PIN		TYPE	DESCRIPTION
NAME	NO.		
I/O1	1	I/O	Surge/ESD protected channels. Connect to the lines being protected.
I/O2	3		
I/O3	4		
I/O4	5		
GND	2	GND	Ground. Connect to ground

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
IEC 61000-4-4 Electrical Fast Transient	Peak Power at 25 °C		80	A
IEC 61000-4-5 Surge (t <sub>p</sub> 8/20 μs)	Peak Power at 25 °C		85	W
	Peak Current at 25 °C		12	A
T <sub>A</sub>	Operating free-air temperature	–40	125	°C
T <sub>stg</sub>	Storage temperature	–65	155	°C

- (1) Stresses beyond those listed under *Absolute Maximum Rating* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Condition*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### 6.2 ESD Ratings -JEDEC Specifications

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	±2500	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	±1000	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. [Following sentence optional; see the wiki.] Manufacturing with less than 500-V HBM is possible with the necessary precautions. [Following sentence optional; see the wiki.] Pins listed as ±WWW V and/or ±XXX V may actually have higher performance.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. [Following sentence optional; see the wiki.] Manufacturing with less than 250-V CDM is possible with the necessary precautions. [Following sentence optional; see the wiki.] Pins listed as ±YYY V and/or ±ZZZ V may actually have higher performance.

### 6.3 ESD Ratings - IEC Specifications

			VALUE	UNIT
V <sub>(ESD)</sub>	Electrostatic discharge	IEC 61000-4-2 Contact Discharge, all pins	±30000	V
		IEC 61000-4-2 Air Discharge, all pins	±30000	

### 6.4 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V <sub>IN</sub>	Input voltage	0		3.6	V
T <sub>A</sub>	Operating Free Air Temperature	–40		125	°C

### 6.5 Thermal Information

THERMAL METRIC <sup>(1)</sup>		ESDS302	ESDS304	UNIT
		DBV (SOT-23)	DBV (SOT-23)	
		5 PINS	5 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	176.2	133.5	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	125.7	85.1	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	88.4	49.4	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	71.4	30.1	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	88.2	49.2	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	N/A	°C/W

- (1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics](#) application report.

## 6.6 Electrical Characteristics

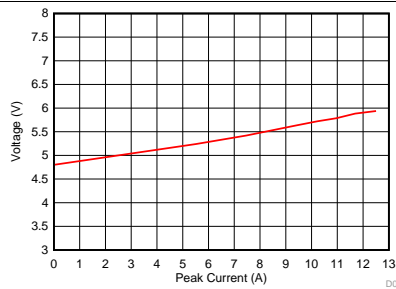
At TA = 25°C unless otherwise noted

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V <sub>RWM</sub>	Reverse stand-off voltage	I <sub>IO</sub> < 500 nA, across operating temperature range			3.6	V
I <sub>LEAKAGE</sub>	Leakage current at 3.6 V	V <sub>IO</sub> = 3.6 V, Any IO pin to GND		3	50	nA
V <sub>BRF</sub>	Breakdown voltage, Any IO pin to GND <sup>(1)</sup>	I <sub>IO</sub> = 1 mA	4.5		7.5	V
V <sub>FWD</sub>	Diode forward voltage, GND to IO pin	I <sub>IO</sub> = 1 mA		0.8		V
V <sub>HOLD</sub>	Holding voltage, Any IO pin to GND <sup>(2)</sup>	I <sub>IO</sub> = 1 mA		5		V
V <sub>CLAMP</sub>	Surge Clamping voltage, t <sub>p</sub> = 8/20 μs	I <sub>PP</sub> = 1 A, Any IO pin to GND		5.1		V
		I <sub>PP</sub> = 12 A, Any IO pin to GND		6		V
		I <sub>PP</sub> = 1 A, GND to any IO pin		1.2		V
		I <sub>PP</sub> = 12 A, GND to any IO pin		3		V
	TLP Clamping Voltage, t <sub>p</sub> = 100 ns	I <sub>PP</sub> = 16 A, any IO to GND pin		5.8		V
		I <sub>PP</sub> = 16 A, GND to any IO pin		3.1		V
C <sub>LINE</sub>	Line capacitance, any IO to GND	V <sub>IO</sub> = 0 V, V <sub>p-p</sub> = 30 mV, f = 1 MHz		2.3	2.8	pF
ΔC <sub>LINE</sub>	Variation of line capacitance	C <sub>LINE1</sub> - C <sub>LINE2</sub> , V <sub>IO</sub> = 0 V, V <sub>p-p</sub> = 30 mV, f = 1 MHz		0.05	0.1	pF
C <sub>CROSS</sub>	Line-to-line capacitance	V <sub>IO</sub> = 0V, V <sub>rms</sub> = 30 mV, f = 1 MHz		1.25	1.5	pF

(1) V<sub>BRF</sub> is defined as the max voltage obtained at 1 mA when sweeping the voltage up, before the device latches into the snapback state

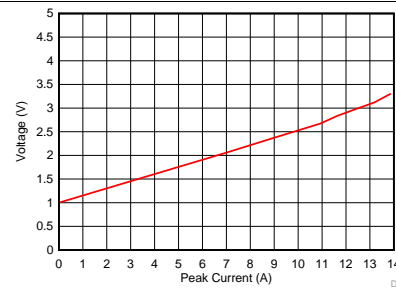
(2) V<sub>HOLD</sub> is defined as the voltage when 1 mA is applied, after the device has successfully latched into the snapback state.

## 6.7 Typical Characteristics



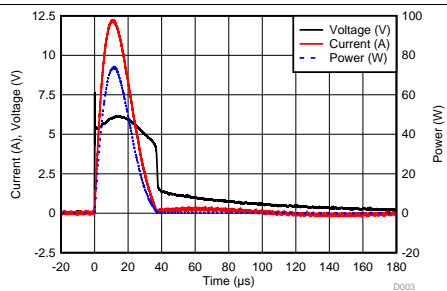
D001\_Vclamp\_Pos.grf

**Figure 1. Surge Clamping Voltage vs. Peak Pulse Current (IEC 61000-4-5,  $t_p = 8/20 \mu s$ ), Any IO Pin to GND**



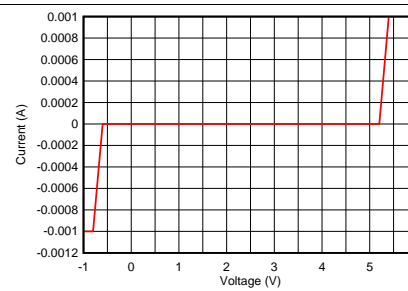
D002\_Vclamp\_Neg.grf

**Figure 2. Surge Clamping Voltage vs. Peak Pulse Current (IEC 61000-4-5,  $t_p = 8/20 \mu s$ ), GND to IO Pin**



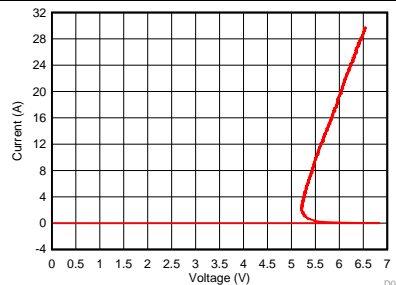
D003\_Surge\_IV.grf

**Figure 3. Surge Current, Clamping Voltage and Power Waveform (IEC-61000-4-5,  $t_p = 8/20 \mu s$ ), Any IO Pin to GND**



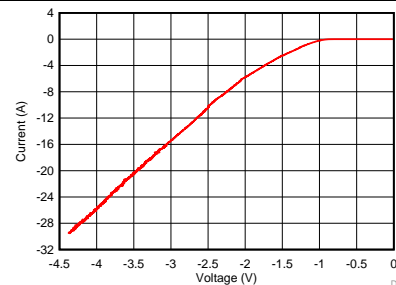
D004\_DC\_Plot.grf

**Figure 4. DC I-V Curve**



D005\_TLP\_Pos.grf

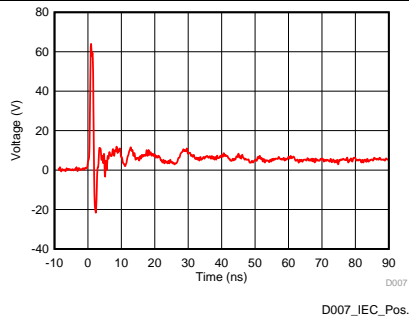
**Figure 5. TLP I-V Curve, IO to GND,  $t_p = 100 ns$**



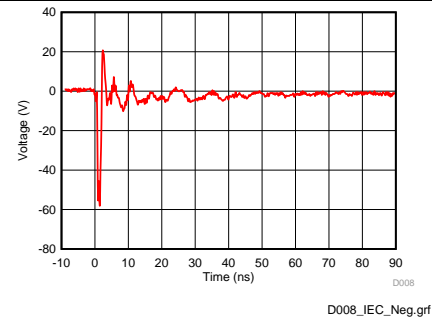
D006\_TLP\_Neg.grf

**Figure 6. TLP I-V Curve, IO to GND Negative,  $t_p = 100 ns$**

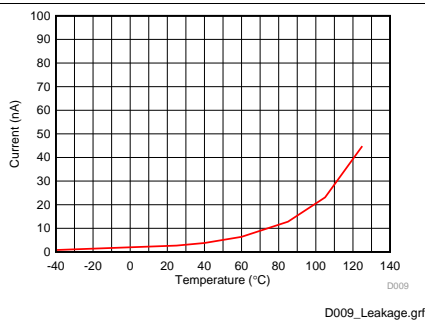
## Typical Characteristics (continued)



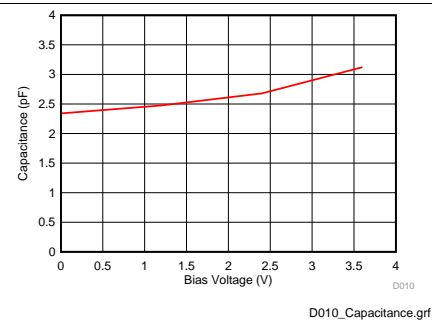
**Figure 7. +8 kV IEC 61000-4-2 Clamping Voltage Waveform, IO Pin to GND**



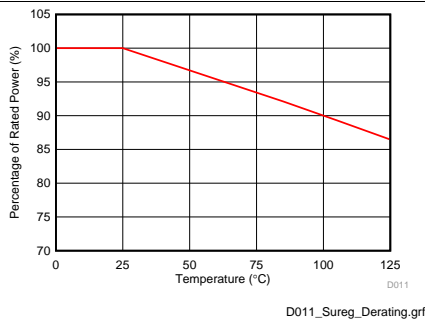
**Figure 8. -8 kV IEC 61000-4-2 Clamping Voltage Waveform, IO Pin to GND**



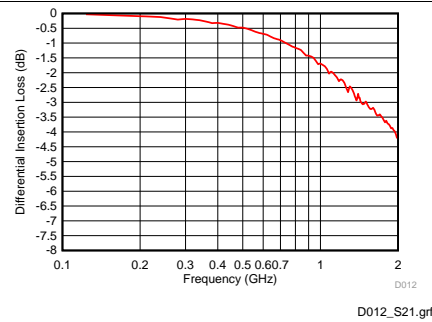
**Figure 9. DC Leakage Current vs. Ambient Temperature, Bias Voltage = 3.6 V**



**Figure 10. Capacitance vs. Bias Voltage at 25°C**



**Figure 11. Surge Power Derating with Respect to Ambient Temperature**



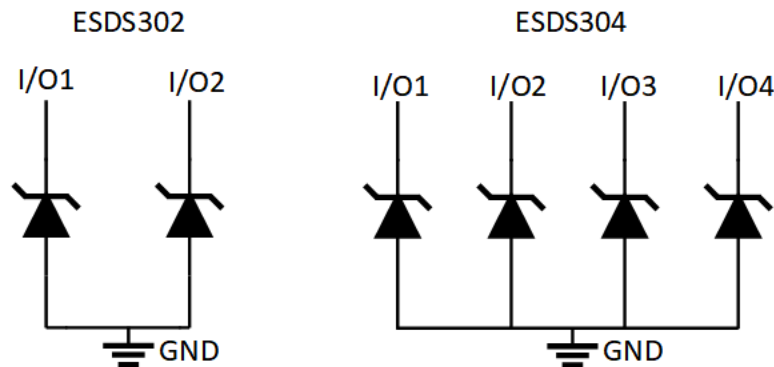
**Figure 12. Differential Insertion Loss vs. Frequency**

## 7 Detailed Description

### 7.1 Overview

The ESDS304, ESDS302 devices are uni-directional ESD Protection Diode with ultra-low capacitance. This device can dissipate ESD strikes above the maximum level specified by the IEC 61000-4-2 International Standard. The ultra-low capacitance makes this device ideal for protecting any super high-speed signal pins.

### 7.2 Functional Block Diagram



### 7.3 Feature Description

The I/O pins of ESDS304 and ESDS302 can withstand surge events (IEC 61000-4-5, 8/20  $\mu$ s waveform) up to 12 A and 85 W. These devices also provide ESD protection up to  $\pm 30$ -kV contact and  $\pm 30$ -kV air gap per IEC 61000-4-2 standard. The I/O pins can withstand an electrical fast transient burst of up to 80 A (IEC 61000-4-4 5/50 ns waveform, 4 kV with 50- $\Omega$  impedance). The capacitance between each I/O pin to ground is 2.3 pF (typical) and 2.8 pF (maximum). This device supports data rates up to 1 Gbps. The reverse DC breakdown voltage of each I/O pin is a minimum of 4.5 V. This ensures that sensitive equipment is protected from surges above the reverse standoff voltage of 3.6 V. The I/O pins feature an ultra-low leakage current of 50 nA (maximum) with a bias of 3.6 V. This device features an industrial operating range of  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$ .

### 7.4 Device Functional Modes

The ESDS304, ESDS302 devices are a passive integrated circuit that triggers when voltages are above  $V_{BRF}$  or below 0.7 V. During ESD events, voltages as high as  $\pm 30$  kV (air) can be directed to ground via the internal diode network. When the voltages on the protected line fall below the trigger levels of ESDS304, ESDS302 (usually within a few nano-seconds) the devices reverts to passive.



## 8 Application and Implementation

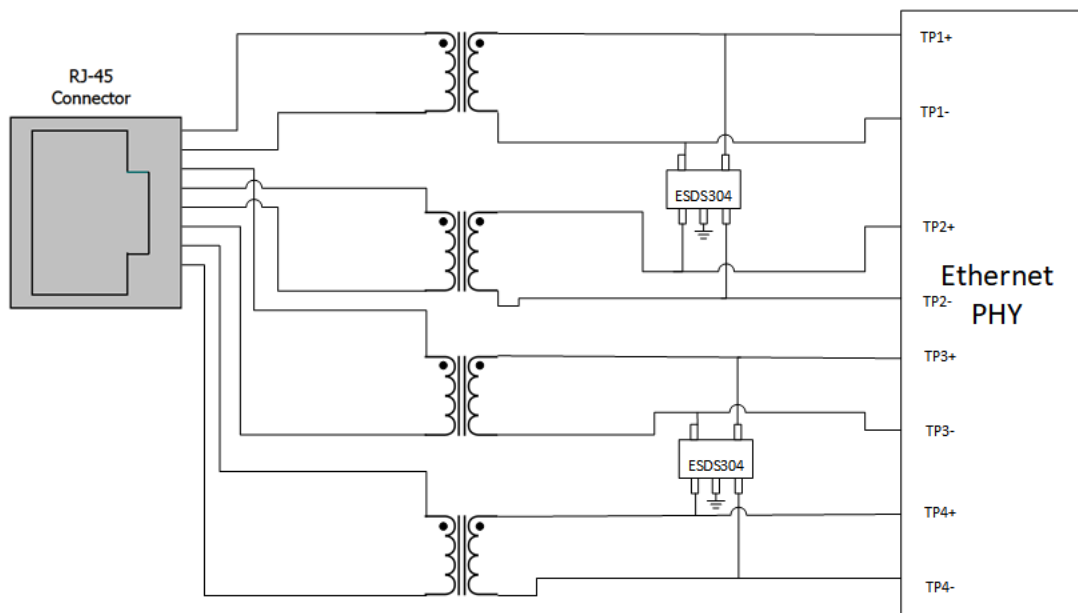
### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

The ESDS304, ESDS302 devices are diode type TVS which is used to provide a path to ground for dissipating ESD events on high-speed signal lines between a human interface connector and a system. As the current from ESD passes through the TVS, only a small voltage drop is present across the diode. This is the voltage presented to the protected IC. The low  $R_{DYN}$  of the triggered TVS holds this voltage,  $V_{CLAMP}$ , to a safe level for the protected IC.

### 8.2 Typical Application



**Figure 13. ESDS304 Protecting the Ethernet 1G Interface**

#### 8.2.1 Design Requirements

A typical operation for the ESDS304 would be protecting a high speed dataline similar to one shown in Figure 13. In this example, the ESDS304 is protecting an Ethernet PHY's data lines that has a nominal operating voltage of 3.6 V. Many of the Ethernet interfaces that connect to long cables require protection against  $\pm 1$  kV surge test through a  $42\text{-}\Omega$  coupling resistor and a  $0.5\text{ }\mu\text{F}$  capacitor, equaling roughly 24 A of surge current. Without any input protection, if a surge event is caused by lightning, coupling, ringing, or any other fault condition, this input voltage will rise to hundreds of volts for multiple microseconds, harming the device. For Ethernet 1000Base-T (1Gbps), application design parameters listed in Table 1 are known.

**Table 1. Design Parameters**

DESIGN PARAMETER	VALUE
Single ended signal voltage range on differential data line pairs	0 to 3.6 V
Operating Frequency	125 MHz

## 8.2.2 Detailed Design Procedure

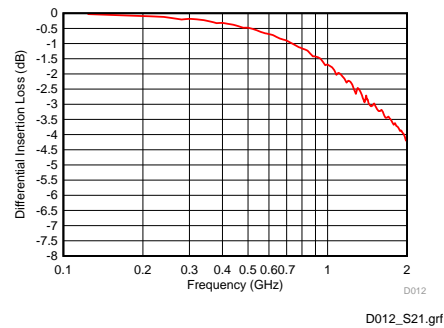
### 8.2.2.1 Signal Range

The ESDS304 has 4 identical surge protection channels with each channel supporting a signal range of 0 to 3.6 V. The device will work well with any Ethernet PHY that drives the single ended voltage on the data line up to a 3.6 V.

### 8.2.2.2 Operating Frequency

The ESDS304 has a capacitance of 2.3 pF (typical) and can support the 125 MHz operation of Ethernet 1000Base-T application

## 8.2.3 Application Curves



**Figure 14. Differential Insertion Loss vs. Frequency**

## 9 Power Supply Recommendations

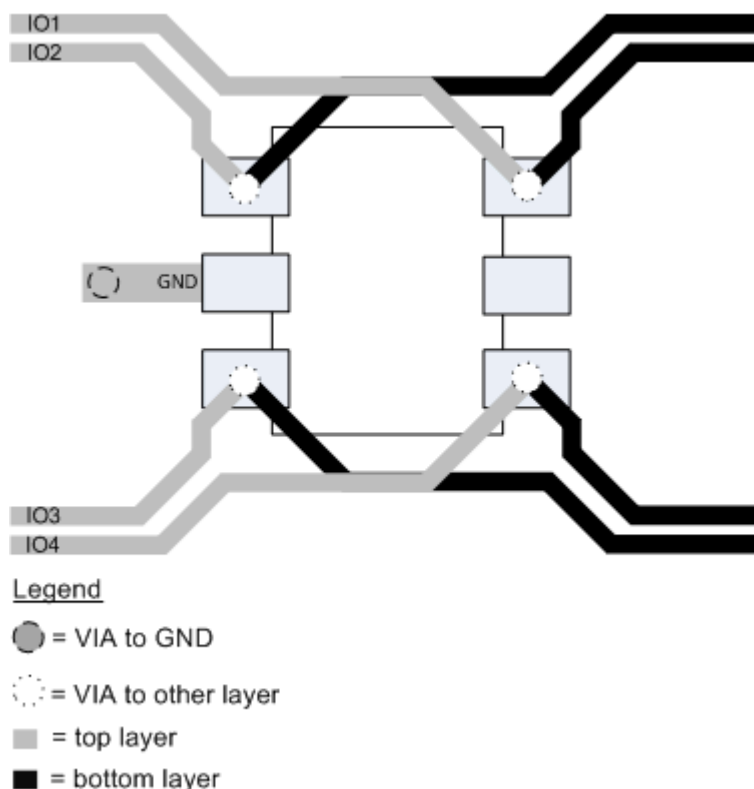
The ESDS304, ESDS302 devices are passive ESD devices and there is no need to power them. Take care not to violate the recommended I/O specification (0 V to 3.6 V) to ensure the device functions properly.

## 10 Layout

### 10.1 Layout Guidelines

- The optimum placement is as close to the connector as possible.
  - EMI during an ESD event can couple from the trace being struck to other nearby unprotected traces, resulting in early system failures.
  - The PCB designer must minimize the possibility of EMI coupling by keeping any unprotected traces away from the protected traces which are between the TVS and the connector.
- Route the protected traces as straight as possible.
- Eliminate any sharp corners on the protected traces between the TVS and the connector by using rounded corners with the largest radii possible.
  - Electric fields tend to build up on corners, increasing EMI coupling.

### 10.2 Layout Examples



**Figure 15. Layout Example for the 4-channel Device, ESDS304**

## 11 Device and Documentation Support

### 11.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to order now.

**Table 2. Related Links**

PARTS	PRODUCT FOLDER	ORDER NOW	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
ESDS302	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>
ESDS304	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>	<a href="#">Click here</a>

### 11.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. In the upper right corner, click on *Alert me* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

### 11.3 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 11.4 Trademarks

E2E is a trademark of Texas Instruments.

### 11.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
ESDS302DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	1R5B	<a href="#">Samples</a>
ESDS304DBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 125	1R3B	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

**RoHS Exempt:** TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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**TAPE AND REEL INFORMATION**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ESDS302DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3
ESDS304DBVR	SOT-23	DBV	5	3000	178.0	9.0	3.3	3.2	1.4	4.0	8.0	Q3

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ESDS302DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0
ESDS304DBVR	SOT-23	DBV	5	3000	180.0	180.0	18.0

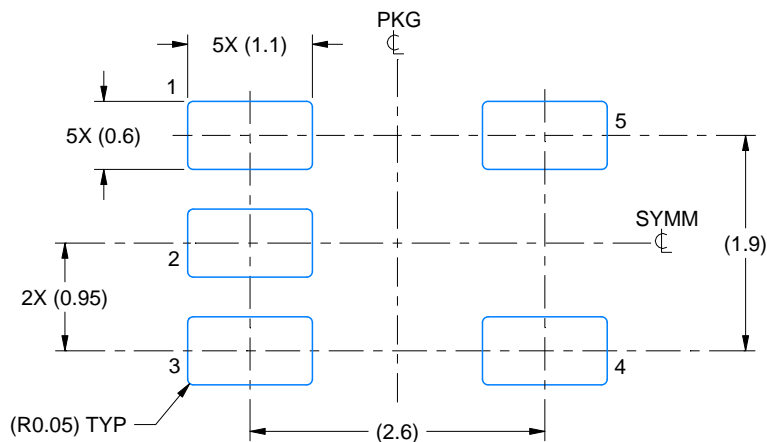




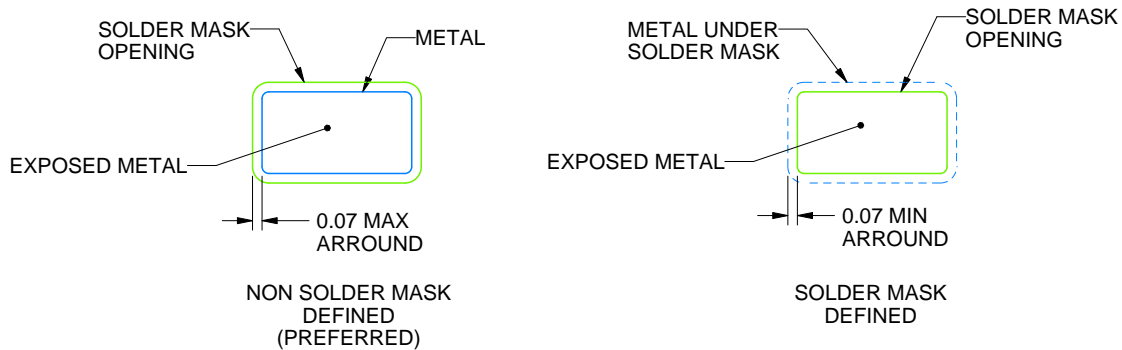
**DBV0005A**

## SOT-23 - 1.45 mm max height

## SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



## SOLDER MASK DETAILS

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NOTES: (continued)

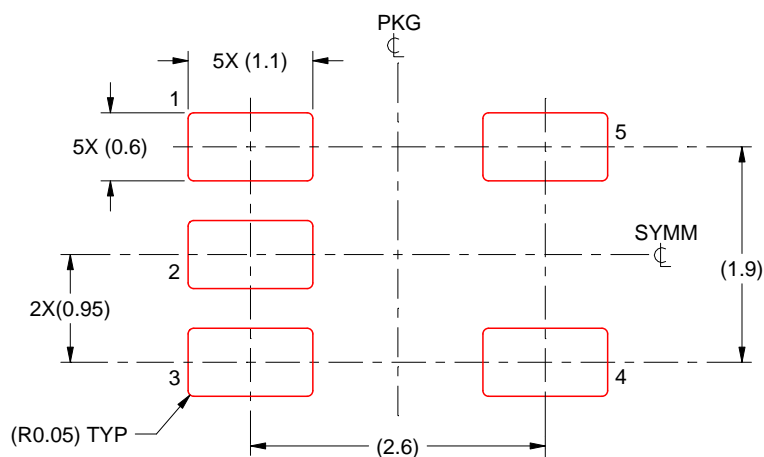
5. Publication IPC-7351 may have alternate designs.  
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

## EXAMPLE STENCIL DESIGN

DBV0005A

SOT-23 - 1.45 mm max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
8. Board assembly site may have different recommendations for stencil design.

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